

(TLP621)

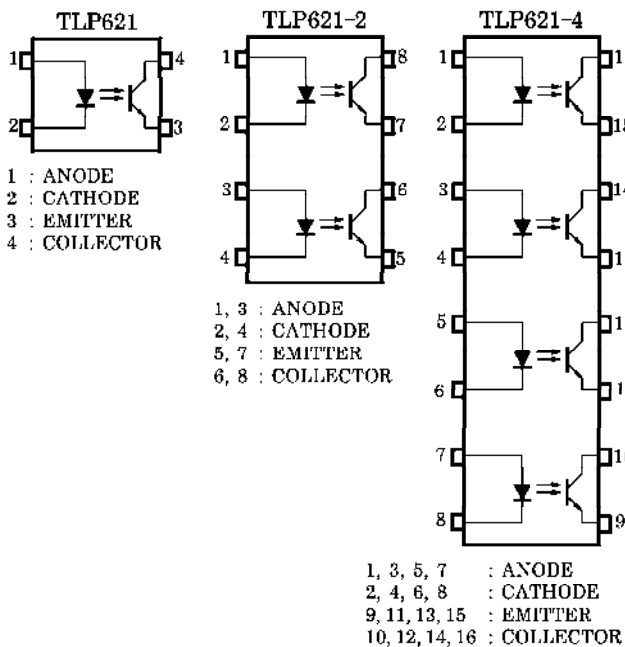
PROGRAMMABLE CONTROLLER
 AC/DC - INPUT MODULE
 SOLID STATE RELAY

The TOSHIBA TLP621, -2, and -4 consists of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode.

The TLP621-2 offers two isolated channels in an eight lead plastic DIP package, which the TLP621-4 provides four isolated channels in a sixteen plastic DIP package.

- Collector-Emitter Voltage : 55V (Min.)
 - Current Transfer Ratio : 50% (Min.)
- Rank GB : 100% (Min.)

PIN CONFIGURATIONS (TOP VIEW)



Unit in mm

<p>TLP621 Weight : 0.26g</p>	
JEDEC	—
EIAJ	—
TOSHIBA	11-5B2
<p>TLP621-2 Weight : 0.54g</p>	
JEDEC	—
EIAJ	—
TOSHIBA	11-10C4
<p>TLP621-4 Weight : 1.1g</p>	
JEDEC	—
EIAJ	—
TOSHIBA	11-20A3

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● Current Transfer Ratio

TYPE	CLASSI- FICATION *1	CURRENT TRANSFER RATIO (%) (I_C / I_F)		MARKING OF CLASSIFICATION
		$I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$, $T_a = 25^\circ\text{C}$		
		MIN.	MAX.	
TLP621	(None)	50	600	BLANK, Y, Y [■] , G, G [■] , B, B [■] , GB
	Rank Y	50	150	Y, Y [■]
	Rank GR	100	300	G, G [■]
	Rank BL	200	600	B, B [■]
	Rank GB	100	600	G, G [■] , B, B [■] , GB
TLP621-2	(None)	50	600	BLANK, GR, BL, GB
TLP621-4	Rank GB	100	600	GR, BL, GB

*1 : Ex. Rank GB : TLP621 (GB)

Note : Application type name for certification test, please use standard product type name, i.e.

TLP621 (GB) : TLP621
TLP621-2 (GB) : TLP621-2

- UL Recognized : UL1577, File No. E67349
- BSI Approved : BS415 : 1990, BS7002 : 1989 (EN60950), Certificate No. 6508
Isolation Voltage : 5000V_{rms} (Min.)
- Option (D4) type
VDE Approved : DIN VDE0884 / 08.87, Certificate No. 68384
Maximum Operating Insulation Voltage : 630V_{PK}
Highest Permissible Over Voltage : 6000V_{PK}

(Note) When a VIDE0884 approved type is needed, please designate the "Option (D4)"

- Creepage Distance : 6.4mm (Min.)
- Clearance : 6.4mm (Min.)
- Insulation Thickness : 0.4mm (Min.)

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING		UNIT
			TLP621	TLP621-2 TLP621-4	
LED	Forward Current	I_F	60	50	mA
	Forward Current Derating	$\Delta I_F / ^\circ\text{C}$	-0.7 (Ta > 39°C)	-0.5 (Ta = 25°C)	mA / °C
	Pulse Forward Current	I_{FP}	1 (100 μ s pulse, 100pps)		A
	Power Dissipation	P_D	100	70	mW
	Power Dissipation Derating	$\Delta P_D / ^\circ\text{C}$	-1.0	-0.7	mW / °C
	Reverse Voltage	V_R	5		V
	Junction Temperature	T_j	125		°C
DETECTOR	Collector-Emitter Voltage	V_{CEO}	55		V
	Emitter-Collector Voltage	V_{ECO}	7		V
	Collector Current	I_C	50		mA
	Collector Power Dissipation (1 Circuit)	P_C	150	100	mW
	Collector Power Dissipation Derating (1 Circuit, Ta \geq 25°C)	$\Delta P_C / ^\circ\text{C}$	-1.5	-1.0	mW / °C
	Junction Temperature	T_j	125		°C
Storage Temperature Range		T_{stg}	-55~150		°C
Operating Temperature Range		T_{opr}	-55~100		°C
Lead Soldering Temperature		T_{sol}	260 (10s)		°C
Total Package Power Dissipation		P_T	250	150	mW
Total Package Power Dissipation Derating (Ta \geq 25°C)		$\Delta P_T / ^\circ\text{C}$	-2.5	-1.5	mW / °C
Isolation Voltage (Note 1)		BV_S	5000 (AC, Imin., R.H. \leq 60%)		V_{rms}

Note 1 : Device considered a two terminal : LED side pins shorted together, and DETECTOR side pins shorted together.

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INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.5\text{mA}$	55	—	—	V
	Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	$I_E = 0.1\text{mA}$	7	—	—	V
	Collector Dark Current	I_{CEO}	$V_{CE} = 24\text{V}$	—	10	100	nA
			$V_{CE} = 24\text{V}, T_a = 85^\circ\text{C}$	—	2	50	μA
Capacitance (Collector to Emitter)	C_{CE}	$V = 0, f = 1\text{MHz}$	—	10	—	pF	

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I_C / I_F	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_F(\text{sat})$	$I_F = 1\text{mA}, V_{CE} = 0.4\text{V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 2.4\text{mA}, I_F = 8\text{mA}$	—	—	0.4	V
		$I_C = 0.2\text{mA}, I_F = 1\text{mA}$	—	0.2	—	
		Rank GB	—	—	0.4	

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500\text{V}$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	5000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V_{dc}

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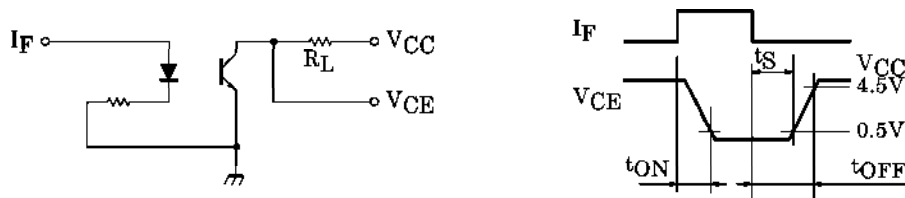
SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	t_r	$V_{CC} = 10V, I_C = 2mA$ $R_L = 100\Omega$	—	2	—	μs
Fall Time	t_f		—	3	—	
Turn-on Time	t_{on}		—	3	—	
Turn-off Time	t_{off}		—	3	—	
Turn-on Time	t_{ON}	$R_L = 1.9k\Omega$ (Fig.1) $V_{CC} = 5V, I_F = 16mA$	—	2	—	μs
Storage Time	t_S		—	15	—	
Turn-off Time	t_{OFF}		—	25	—	

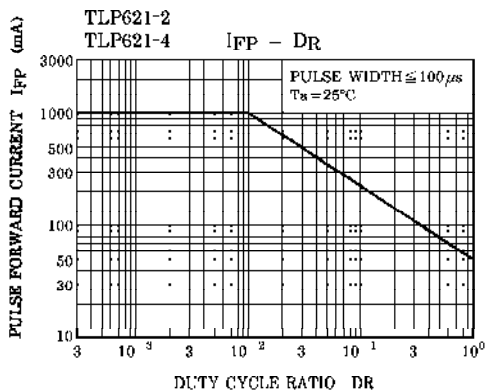
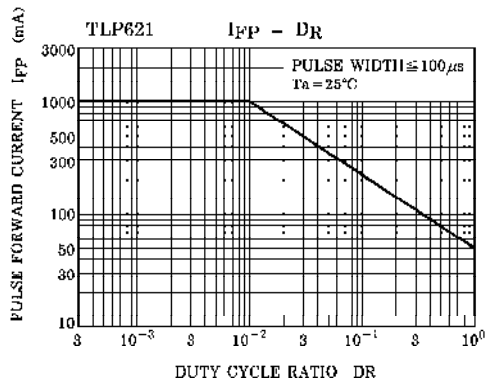
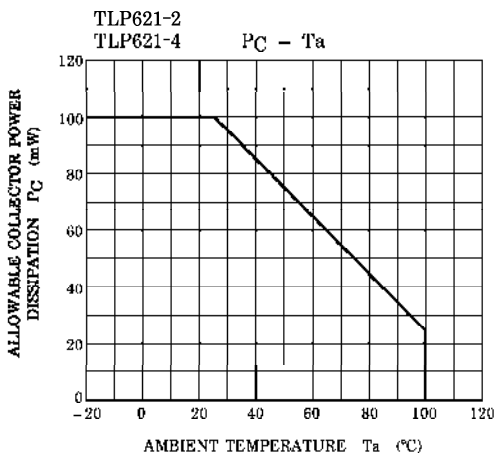
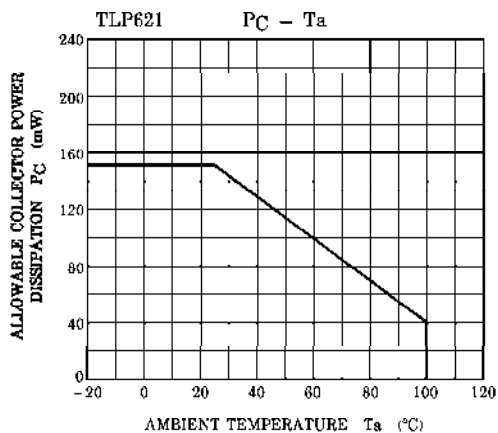
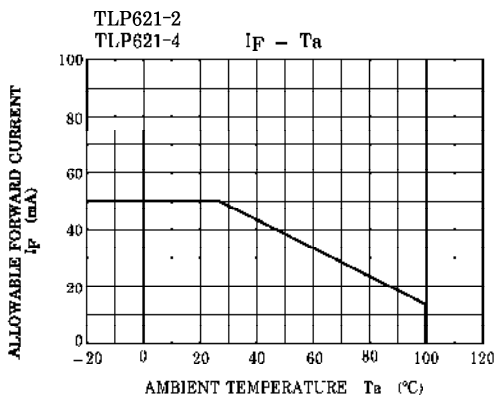
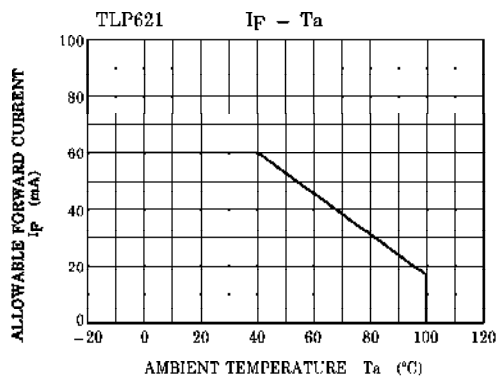
RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{CC}	—	5	24	V
Forward Current	I_F	—	16	20	mA
Collector Current	I_C	—	1	10	mA
Operating Temperature	T_{opr}	-25	—	85	°C

Fig.1 SWITCHING TIME TEST CIRCUIT

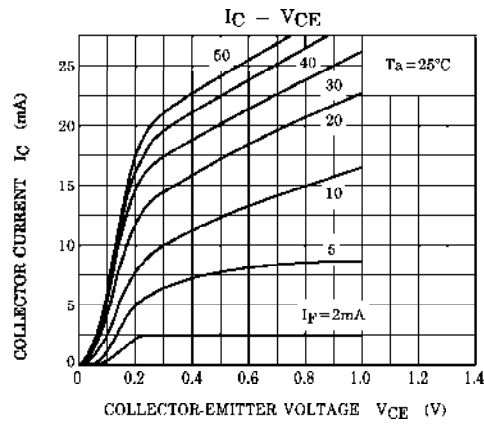
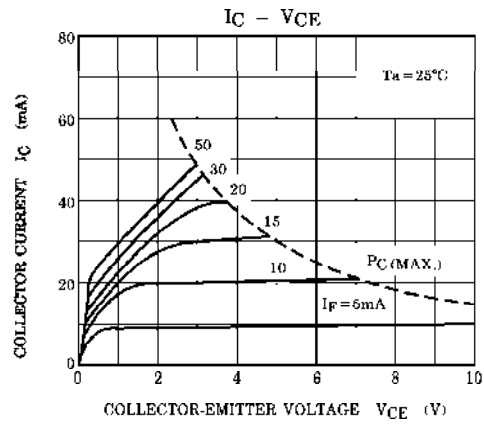
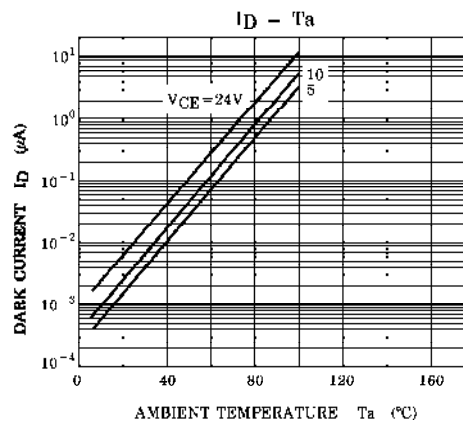
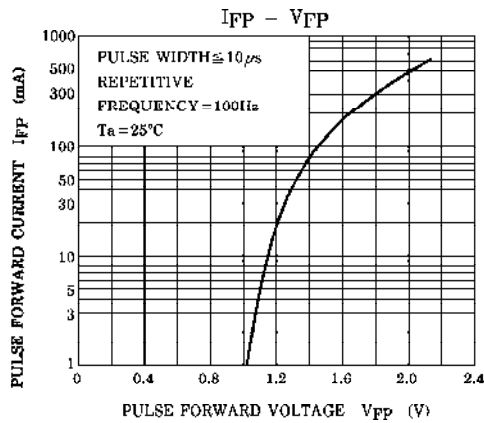
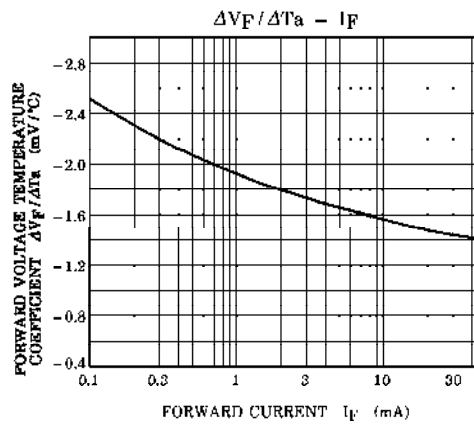
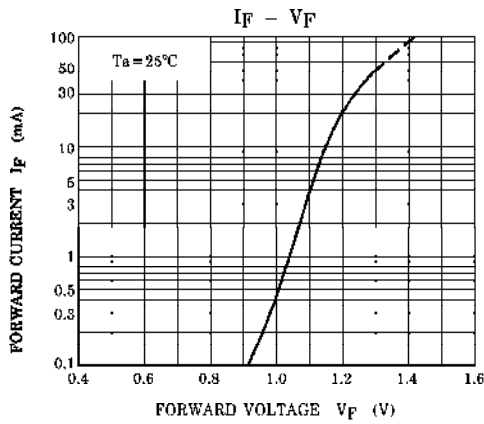


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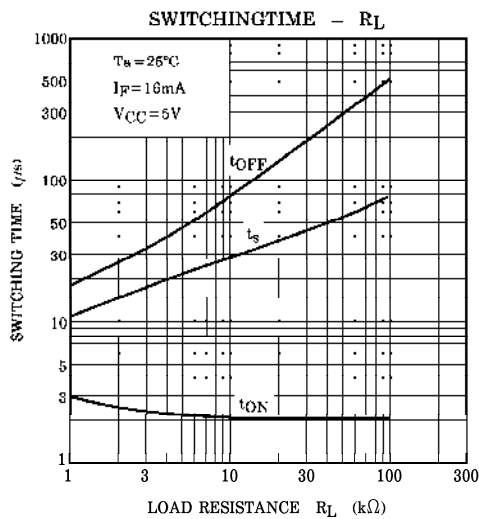
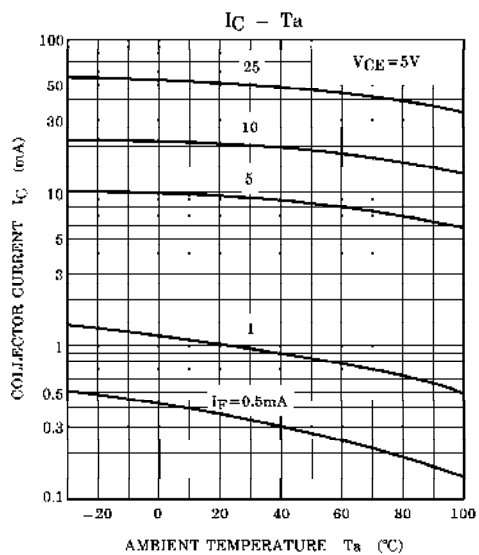
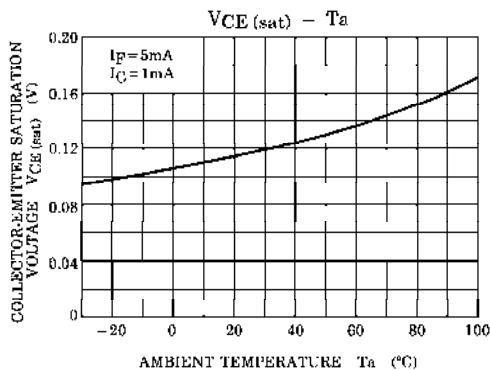
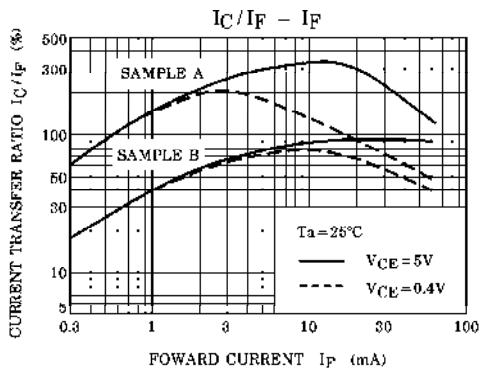
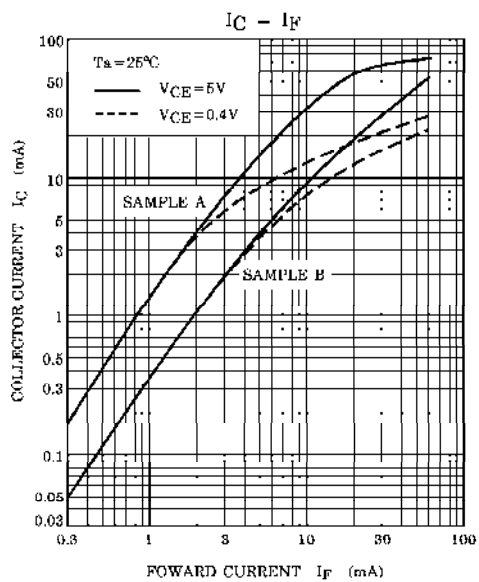
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